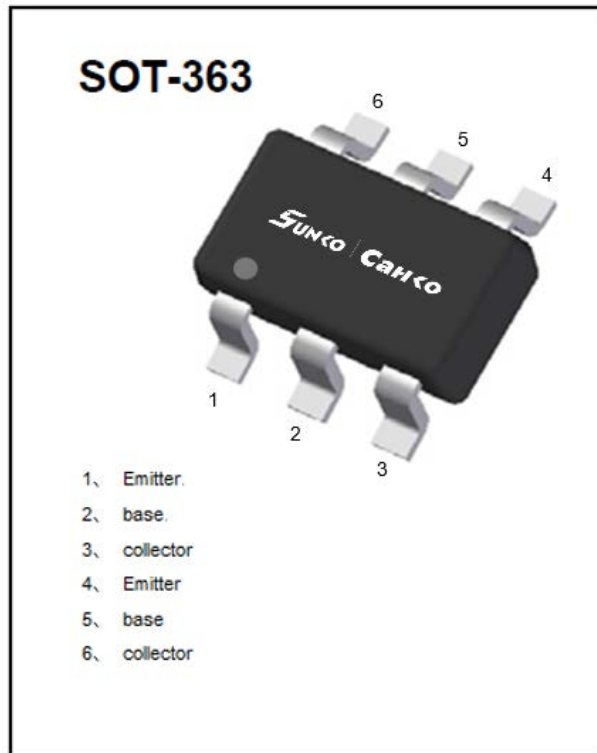


Dual NPN+PNP Small Signal Transistor



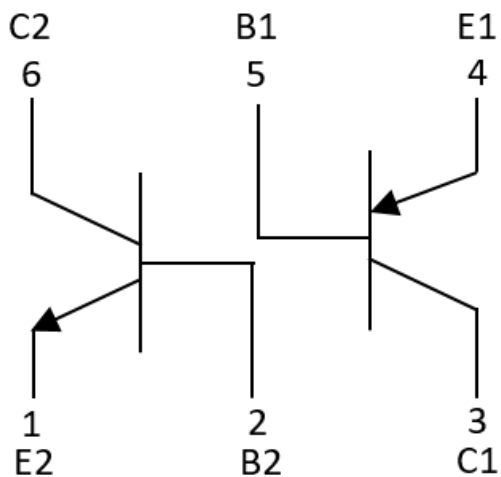
Features

- Epoxy meets UL-94 V-0 flammability rating
- Surface mount package ideally Suited for Automatic Insertion
- NPN/PNP

Mechanical Data

- **Package:** SOT-363
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Marking:** KNM

Equivalent circuit



Ordering Information (Example)

PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MMDT5451	F2	Approximate 0.009g	3000	30000	120000	7" reel

MMDT5451

■TR1 PNP Pin3、4、5 Maximum Ratings (Ta=25℃ Unless otherwise specified)

Item	Symbol	Unit	Conditions	Value
Collector-Base Voltage	VCBO	V	IC=-100μA,IE=0	-160
Collector-Emitter Voltage	VCEO	V	IC=-1mA,IB=0	-150
Emitter-Base Voltage	VEBO	V	IE=-10μA,IC=0	-5
Collector Current -Continuous	IC	mA		-200
Total Device Dissipation	PC	mW		200
Junction Temperature	Tj	℃		150
Storage Temperature	TSTG	℃		-55 to +150

■TR1 PNP Pin3、4、5 Electrical Characteristics (Ta=25℃ unless otherwise specified)

Item	Symbol	Unit	Conditions	Min	TYP	Max
Collector-base breakdown voltage	V _{CBO}	V	IC=-100μA,IE=0	-160		
Collector-emitter breakdown voltage	V _{CEO}	V	IC=-1mA,IB=0	-150		
Emitter-base breakdown voltage	V _{EBO}	V	IE=-10μA,IC=0	-5		
Collector cut-off current	I _{CBO}	nA	VCB=-120V,IE=0			-50
Emmitter cut-off current	I _{EBO}	nA	VEB=-3V, IC=0			-50
DC current gain	h _{FE1}		VCE=-5V,IC=-1mA	50		
	h _{FE2}		VCE=-5V,IC=-10mA	100		300
	h _{FE3}		VCE=-5V,IC=-50mA	50		
Collector-emitter saturation voltage	V _{CE(sat)}	V	IC=-10mA,IB=-1mA			-0.2
Collector-emitter saturation voltage	V _{CE(sat)}	V	IC=-50mA,IB=-5mA			-0.5
Base-emitter saturation voltage	V _{BE(sat)}	V	IC=-10mA,IB=-1mA			-1
Base-emitter saturation voltage	V _{BE(sat)}	V	IC=-50mA,IB=-5mA			-1
Transition frequency	f _T	MHz	VCE=-10V,IC=-10mA,f=100MHz	100		300
Output capacitance	Cobo	pF	VCE=-10V,IE=0,f=1MHz			6

MMDT5451

■TR2 NPN Pin1、2、6 Maximum Ratings (Ta=25℃ Unless otherwise specified)

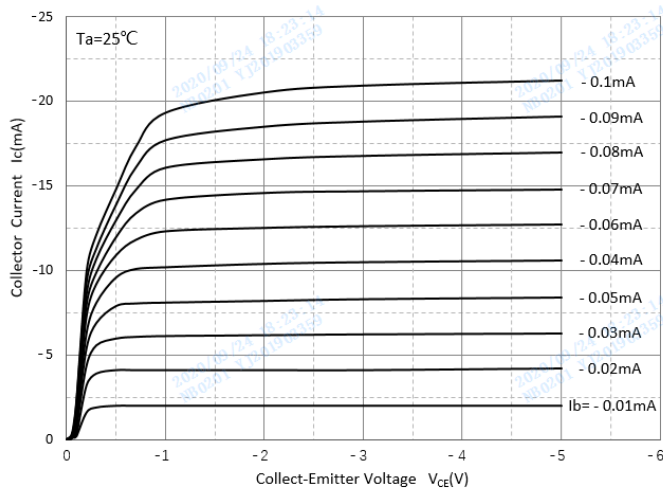
Item	Symbol	Unit	Conditions	Value
Collector-Base Voltage	VCBO	V	IC=100μA,IE=0	180
Collector-Emitter Voltage	VCEO	V	IC=1mA,IB=0	160
Emitter-Base Voltage	VEBO	V	IE=10μA,IC=0	6
Collector Current -Continuous	IC	mA		200
Total Device Dissipation	PC	mW		200
Junction Temperature	Tj	℃		150
Storage Temperature	TSTG	℃		-55 to +150

■TR2 NPN Pin1、2、6 Electrical Characteristics (Ta=25℃ unless otherwise specified)

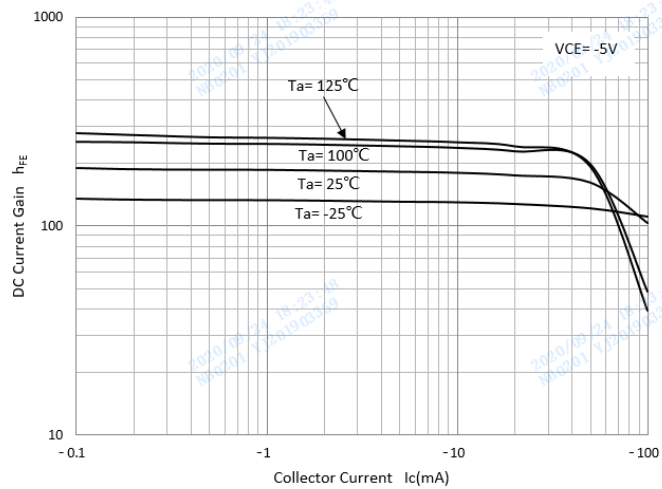
Item	Symbol	Unit	Conditions	Min	TYP	Max
Collector-base breakdown voltage	V _{CBO}	V	IC=100μA,IE=0	180		
Collector-emitter breakdown voltage	V _{CEO}	V	IC=1mA,IB=0	160		
Emitter-base breakdown voltage	V _{EBO}	V	IE=10μA,IC=0	6		
Collector cut-off current	I _{CBO}	nA	VCB=120V,IE=0			50
Emmitter cut-off current	I _{EBO}	nA	VEB=4V, IC=0			50
DC current gain	h _{FE1}		VCE=5V,IC=1mA	80		
	h _{FE2}		VCE=5V,IC=10mA	100		300
	h _{FE3}		VCE=5V,IC=50mA	30		
Collector-emitter saturation voltage	V _{CE(sat)}	V	IC=10mA,IB=1mA			0.15
Collector-emitter saturation voltage	V _{CE(sat)}	V	IC=50mA,IB=5mA			0.2
Base-emitter saturation voltage	V _{BE(sat)}	V	IC=10mA,IB=1mA			1
Base-emitter saturation voltage	V _{BE(sat)}	V	IC=50mA,IB=5mA			1
Transition frequency	f _T	MHz	VCE=10V,IC=10mA,f=100MHz	100		300
Output capacitance	Cobo	pF	VCE=10V,IE=0,f=1MHz			6

■ TR1 PNP Pin3、4、5 Characteristics (Typical)

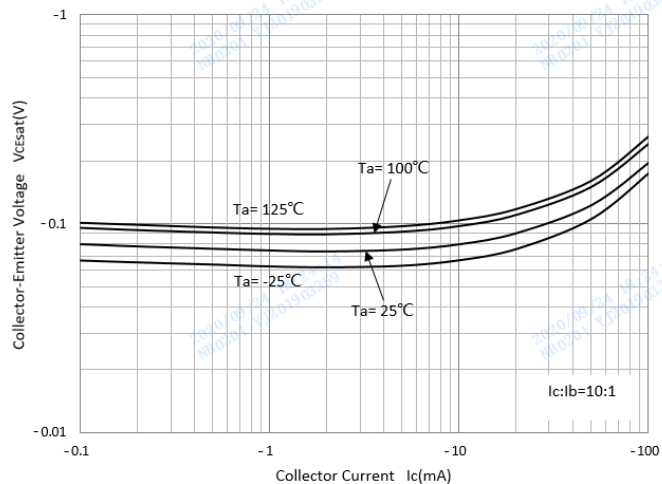
Static Characteristic



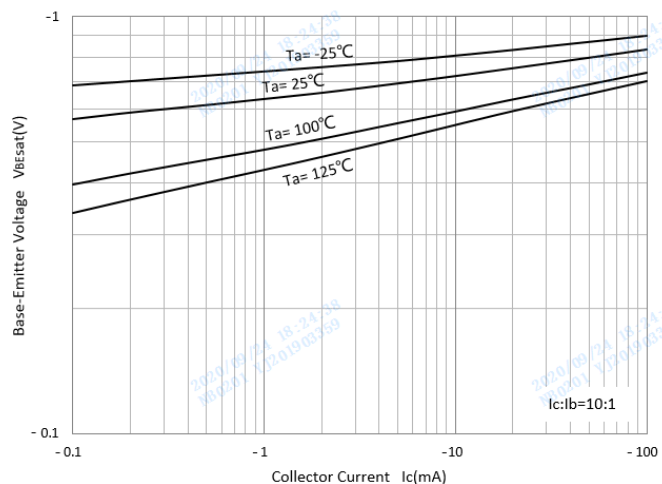
DC Current Gain



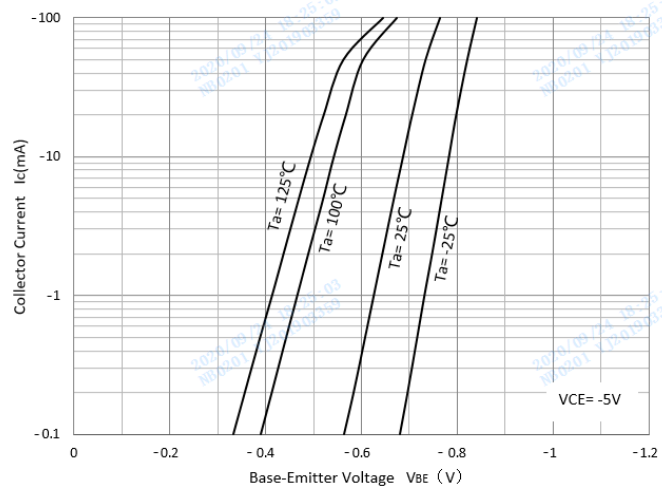
Collector-Emitter Saturation Voltage



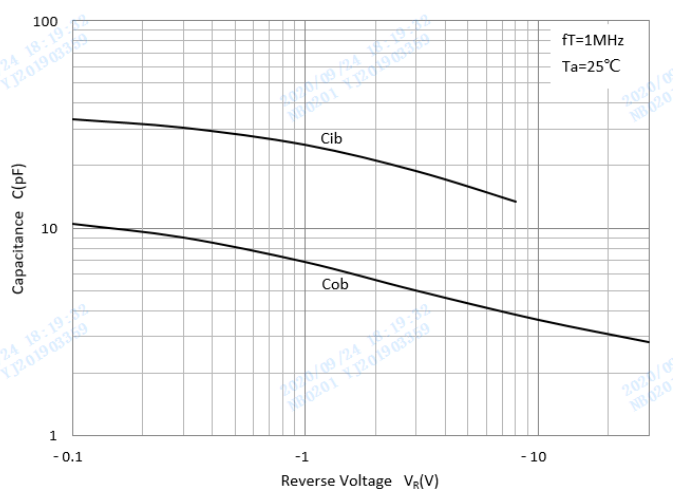
Base-Emitter Saturation Voltage



Base-Emitter On Voltage

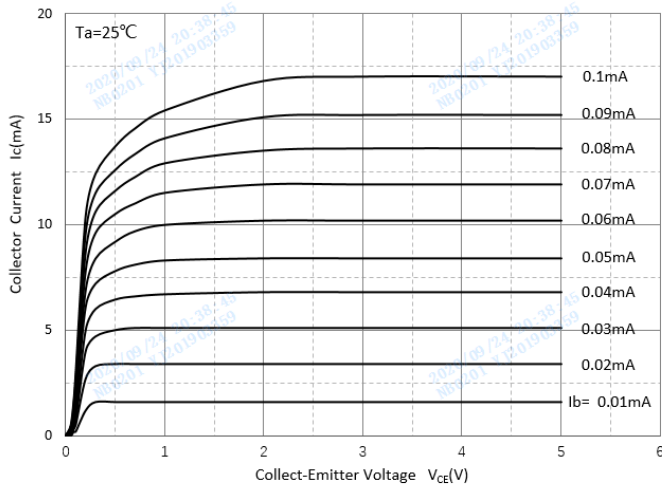


$C_{ob}/C_{ib}-V_{CB}/V_{EB}$

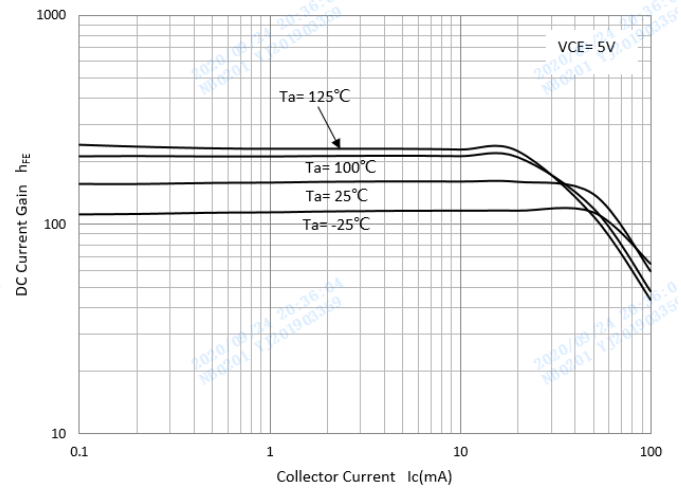


■ TR2 NPN Pin1、2、6 Characteristics (Typical)

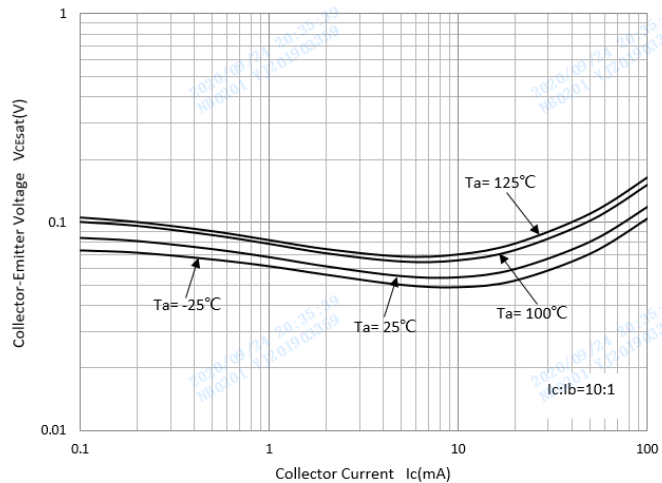
Static Characteristic



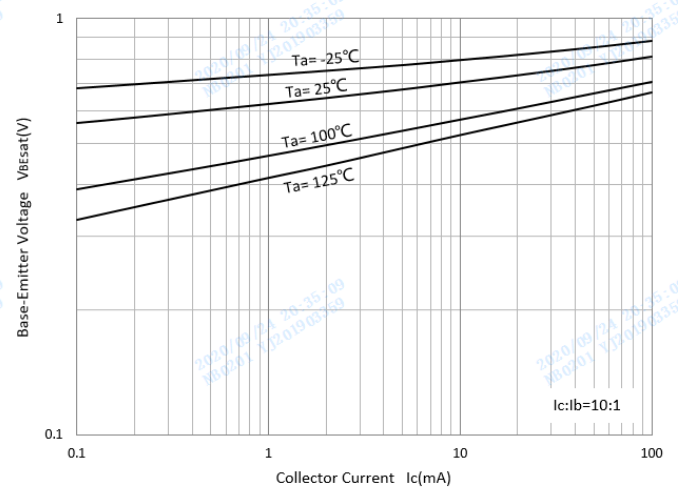
DC Current Gain



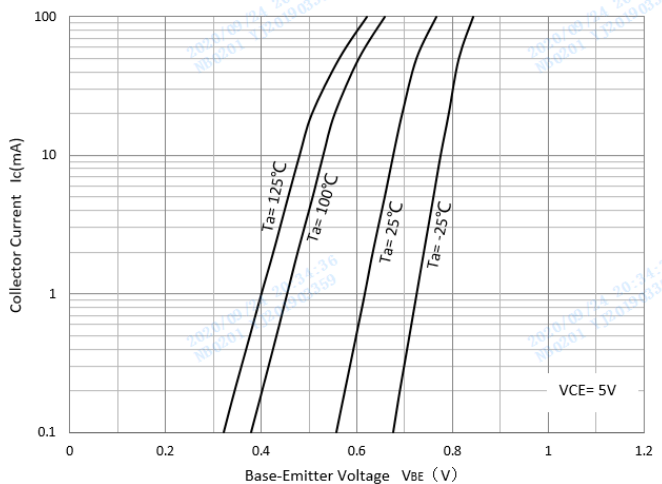
Collector-Emitter Saturation Voltage



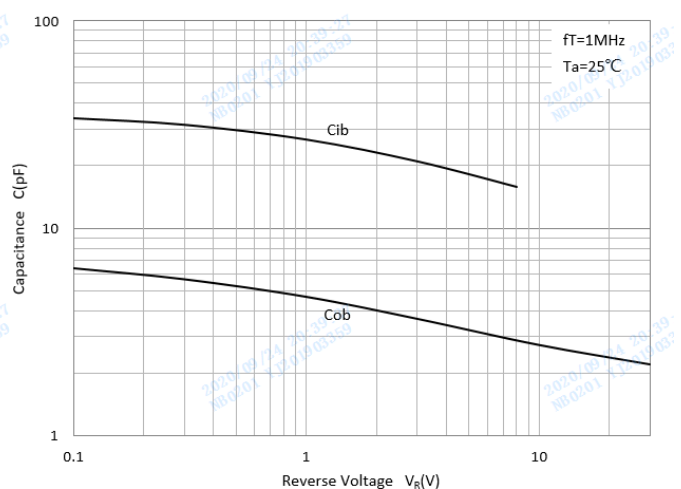
Base-Emitter Saturation Voltage



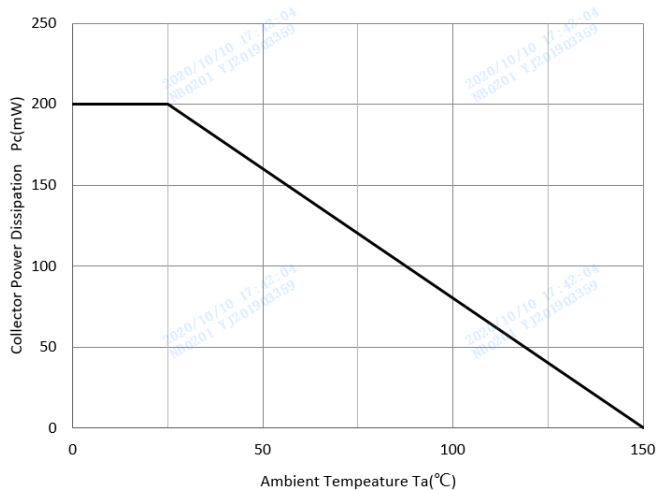
Base-Emitter On Voltage



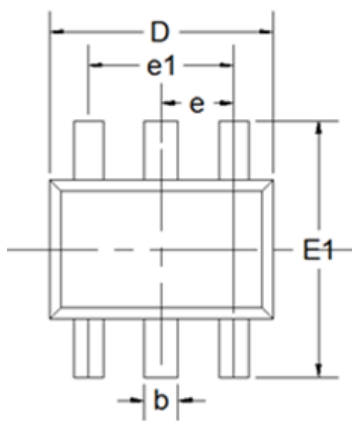
$C_{ob}/C_{ib}-V_{CB}/V_{EB}$



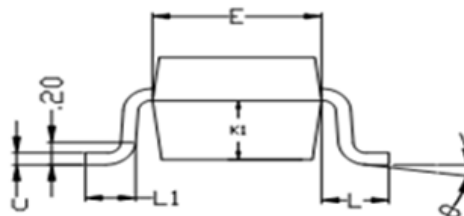
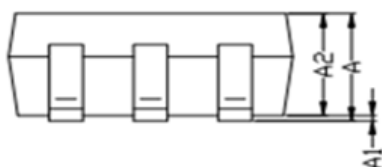
Collector Power Derating Curve



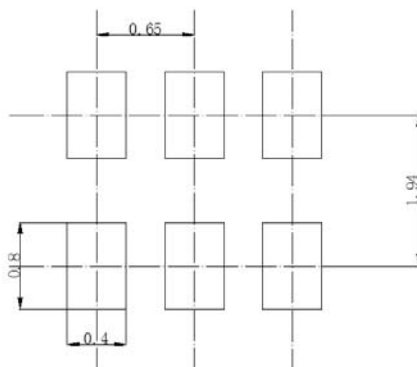
■SOT-363 Package Outline Dimensions



DIM	DIMENSIONS			
	INCHES		MM	
	MIN	MAX	MIN	MAX
A	0.035	0.043	0.9	1.1
A1	0	0.004	0	0.1
A2	0.035	0.039	0.9	1
b	0.006	0.014	0.15	0.35
c	0.002	0.01	0.05	0.25
D	0.071	0.087	1.8	2.2
E	0.045	0.053	1.15	1.35
E1	0.085	0.096	2.15	2.45
e	0.026Typ		0.65Typ	
e1	0.047	0.055	1.2	1.4
L	0.021Typ		0.525Typ	
L1	0.01	0.018	0.26	0.46
θ	0°	8°	0°	8°



■SOT-363 Soldering Footprint



Unit: mm

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